

Fast Recovery Epitaxial Diodes (FRED)

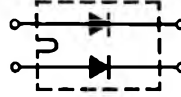
DSEI 2x61

$$I_{FAVM} = 2x60 \text{ A}$$

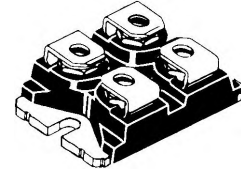
$$V_{RRM} = 1000 \text{ V}$$

$$t_{rr} = 35 \text{ ns}$$

V_{RSM}	V_{RRM}	Type
V	V	
1000	1000	DSEI2x61-10B



miniBLOC, SOT-227 B



Symbol	Test Conditions	Maximum Ratings (per diode)		
I_{FRMS}	$T_{VJ} = T_{VJM}$	100	A	
I_{FAVM}^*	$T_C = 50^\circ\text{C}$; rectangular, $d = 0.5$	60	A	
I_{FRM}	$t_p < 10 \mu\text{s}$; rep. rating, pulse width limited by T_{VJM}	800	A	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	500	A	
		540	A	
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine	450	A	
		480	A	
ji^2dt	$T_{VJ} = 45^\circ\text{C}$	$t = 10 \text{ ms}$ (50 Hz), sine	1150	A^2s
		$t = 8.3 \text{ ms}$ (60 Hz), sine	1200	A^2s
	$T_{VJ} = 150^\circ\text{C}$; $t = 10 \text{ ms}$ (50 Hz), sine $t = 8.3 \text{ ms}$ (60 Hz), sine		1000	A^2s
			950	A^2s
T_{VJ}		-40...+150	$^\circ\text{C}$	
T_{VJM}		150	$^\circ\text{C}$	
T_{stg}		-40...+150	$^\circ\text{C}$	
P_{tot}	$T_C = 25^\circ\text{C}$	180	W	
V_{ISOL}	50/60 Hz, RMS $I_{ISOL} \leq 1 \text{ mA}$	2500	V~	
M_d	Mounting torque	1.5/13	Nm/lb.in.	
	Terminal connection torque (M4)	1.5/13	Nm/lb.in.	
Weight		30	g	

Features

- International standard package miniBLOC (ISOTOP compatible)
- Isolation voltage 2500 V~
- UL registered E 72873
- 2 independent FRED in 1 package
- Planar passivated chips
- Very short recovery time
- Extremely low switching losses
- Low I_{RM} -values
- Soft recovery behaviour

Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses
- Operating at lower temperature or space saving by reduced cooling

Symbol	Test Conditions	Characteristic Values (per diode)	
		typ.	max.
I_R	$T_{VJ} = 25^\circ\text{C}$	$V_R = V_{RRM}$	3 mA
	$T_{VJ} = 25^\circ\text{C}$	$V_R = 0.8 \cdot V_{RRM}$	0.5 mA
	$T_{VJ} = 125^\circ\text{C}$	$V_R = 0.8 \cdot V_{RRM}$	14 mA
V_F	$I_F = 60 \text{ A}$; $T_{VJ} = 150^\circ\text{C}$ $T_{VJ} = 25^\circ\text{C}$		1.8 V
			2.3 V
V_{T0}	For power-loss calculations only	1.43	V
r_T	$T_{VJ} = T_{VJM}$	6.1	$\text{m}\Omega$
R_{thJC} R_{thCK}		0.7	K/W
		0.05	K/W
t_{rr}	$I_F = 1 \text{ A}$; $-di/dt = 200 \text{ A}/\mu\text{s}$; $V_R = 30 \text{ V}$; $T_{VJ} = 25^\circ\text{C}$	35	50 ns
I_{RM}	$V_R = 540 \text{ V}$; $I_F = 60 \text{ A}$; $-di/dt = 480 \text{ A}/\mu\text{s}$ $L \leq 0.05 \mu\text{H}$; $T_{VJ} = 100^\circ\text{C}$	32	36 A

* I_{FAVM} rating includes reverse blocking losses at T_{VJM} , $V_R = 0.8 V_{RRM}$ duty cycle $d = 0.5$
Data according to DIN/IEC 747

IXYS reserves the right to change limits, test conditions and dimensions

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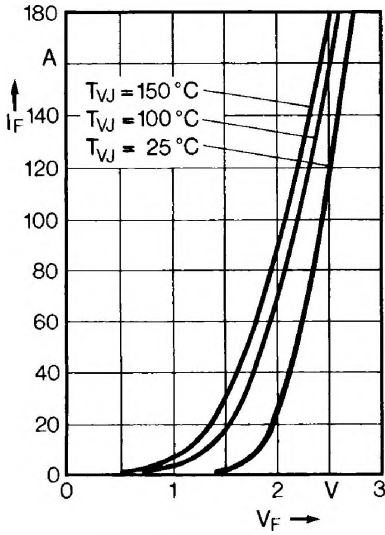


Fig. 1 Forward current versus voltage drop.

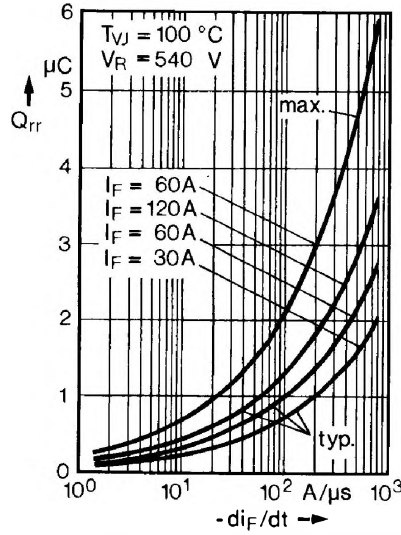


Fig. 2 Recovery charge versus $-di_F/dt$.

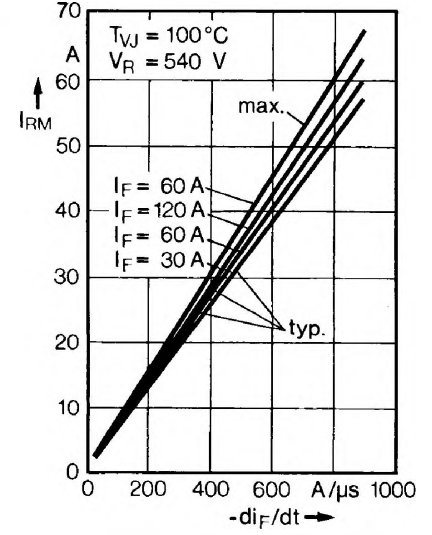


Fig. 3 Peak reverse current versus $-di_F/dt$.

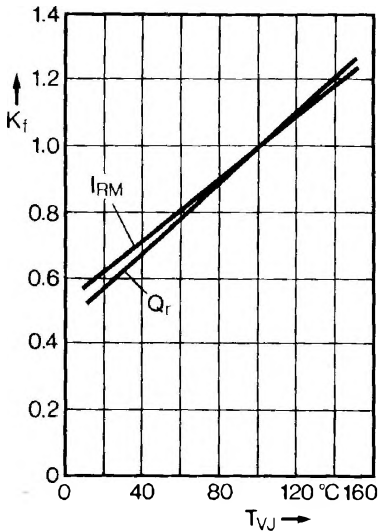


Fig. 4 Dynamic parameters versus junction temperature.

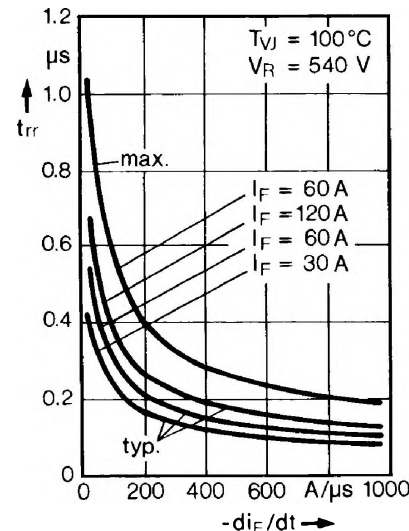


Fig. 5 Recovery time versus $-di_F/dt$.

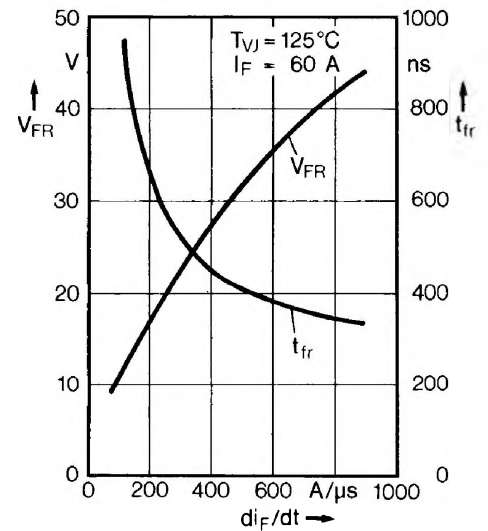


Fig. 6 Peak forward voltage versus $-di_F/dt$.

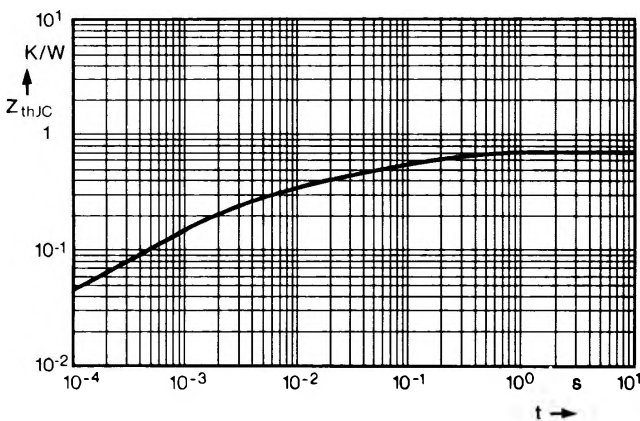
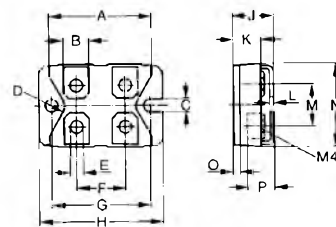


Fig. 7 Transient thermal impedance junction to case.

Dimensions



miniBLOC SOT-227 B
M4 screws (4x) supplied

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	31.5	31.7	1.241	1.249
B	7.8	8.2	0.307	0.323
C	4.0	-	0.158	-
D	4.1	4.3	0.162	0.169
E	4.1	4.3	0.162	0.169
F	14.9	15.1	0.587	0.595
G	30.1	30.3	1.186	1.193
H	38.0	38.2	1.497	1.505
J	11.8	12.2	0.465	0.481
K	8.9	9.1	0.351	0.359
L	0.75	0.85	0.030	0.033
M	12.6	12.8	0.496	0.504
N	25.2	25.4	0.993	1.001
O	1.95	2.05	0.077	0.081
P	-	5.0	-	0.197